

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74HC4051AP, TC74HC4051AF, TC74HC4051AFT**TC74HC4052AP, TC74HC4052AF, TC74HC4052AFT****TC74HC4053AP, TC74HC4053AF, TC74HC4053AFN, TC74HC4053AFT****TC74HC4051AP/AF/AFT 8 - CHANNEL ANALOG MULTIPLEXER / DEMULTIPLEXER****TC74HC4052AP/AF/AFT DUAL 4 - CHANNEL ANALOG MULTIPLEXER / DEMULTIPLEXER****TC74HC4053AP/AF/AFN/AFT TRIPLE 2 - CHANNEL ANALOG MULTIPLEXER / DEMULTIPLEXER**

The TC74HC4051A/4052A/4053A are high speed CMOS ANALOG MULTIPLEXER/DEMULITPLEXER fabricated with silicon gate C²MOS technology. They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The TC74HC4051A has an 8 channel configuration, the TC74HC4052A has a 4 channel×2 configuration and the TC74HC4053A has a 2 channel×3 configuration.

The digital signal to the control terminal turns "ON" the corresponding switch of each channel a large amplitude signal (V_{CC} - V_{EE}) can then be switched by the small logical amplitude (V_{CC} -GND) control signal.

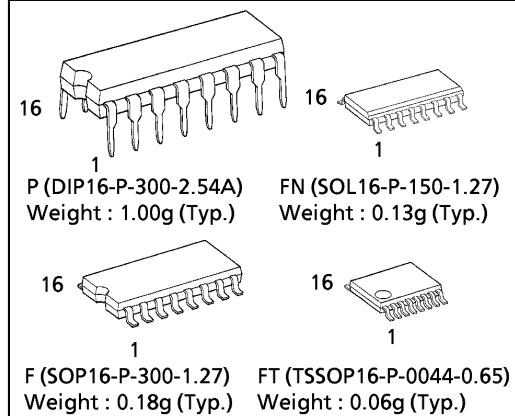
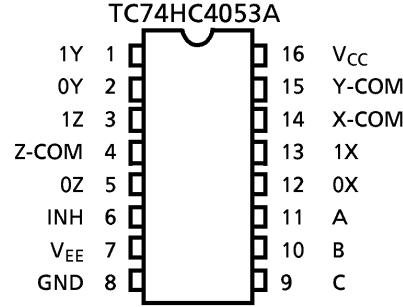
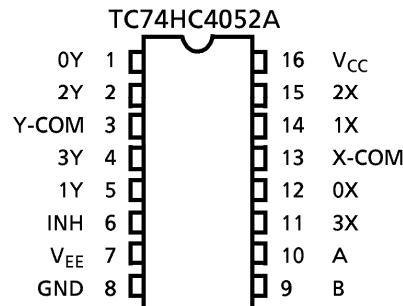
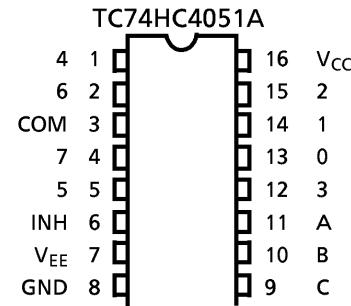
For example, in the case of $V_{CC}=5V$, $GND=0V$, $V_{EE}=-5V$, signals between -5V and +5V can be switched from the logical circuit with a single power supply of 5V. As the ON-resistance of each switch is low, they can be connected to circuits with low input impedance.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES :

- High Speed..... $t_{pd} = 15\text{ns}(\text{typ.})$ at $V_{CC} = 5V$
 $V_{EE} = 0V$
- Low Power Dissipation..... $I_{CC} = 4\mu\text{A}(\text{Max.})$ at $T_a = 25^\circ\text{C}$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\%$ V_{CC} (Min.)
- Low ON Resistance..... $R_{ON} = 50\Omega$ (typ.)
at $V_{CC}-V_{EE} = 9V$
- High Noise Immunity..... $\text{THD} = 0.02\%$ (typ.)
at $V_{CC}-V_{EE} = 9V$
- Pin and Function Compatible with 4051/4052/4053B

(Note) The JEDEC SOP (FN) is not available in Japan.

**PIN ASSIGNMENT**

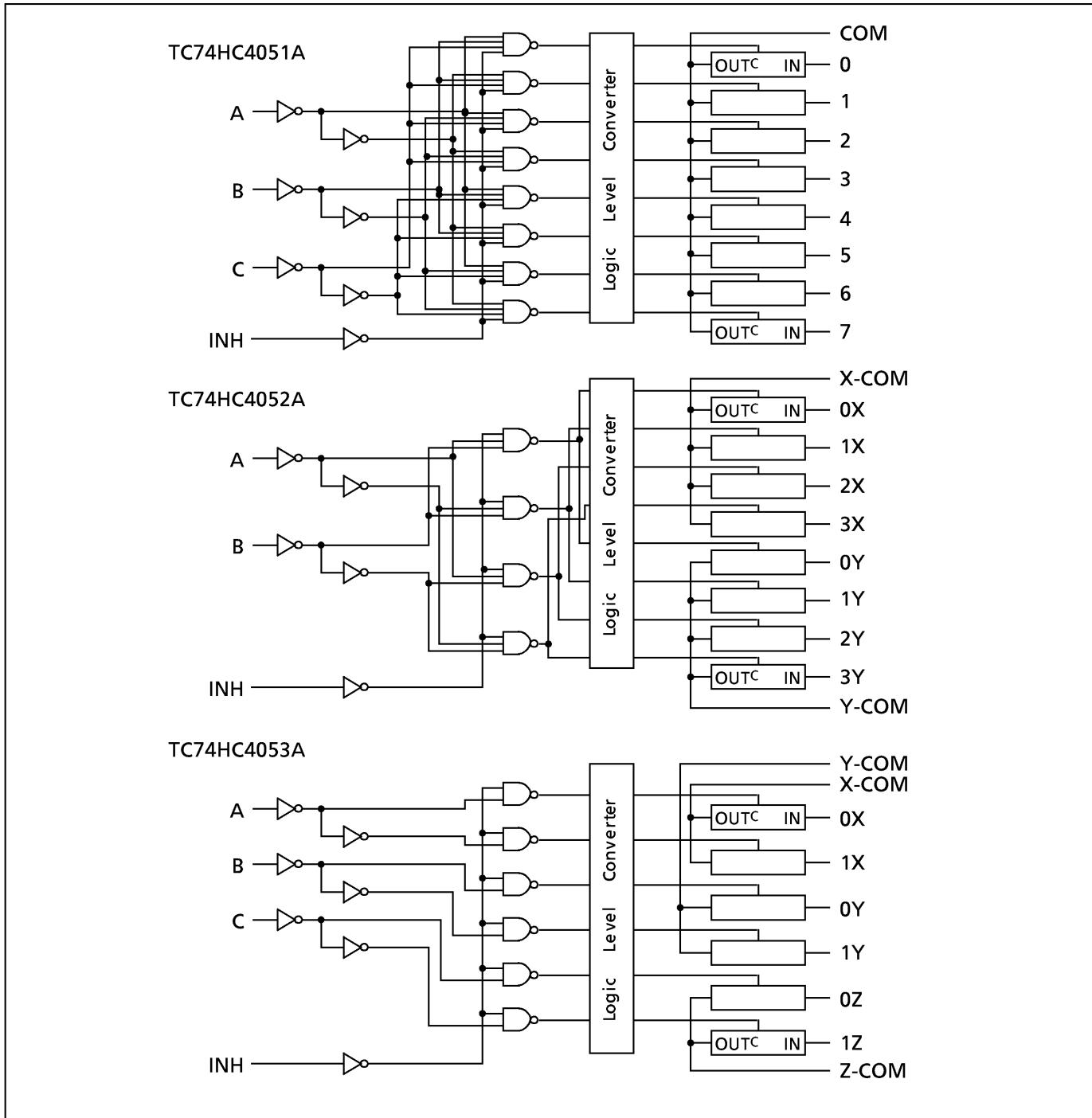
(TOP VIEW)

TRUTH TABLE

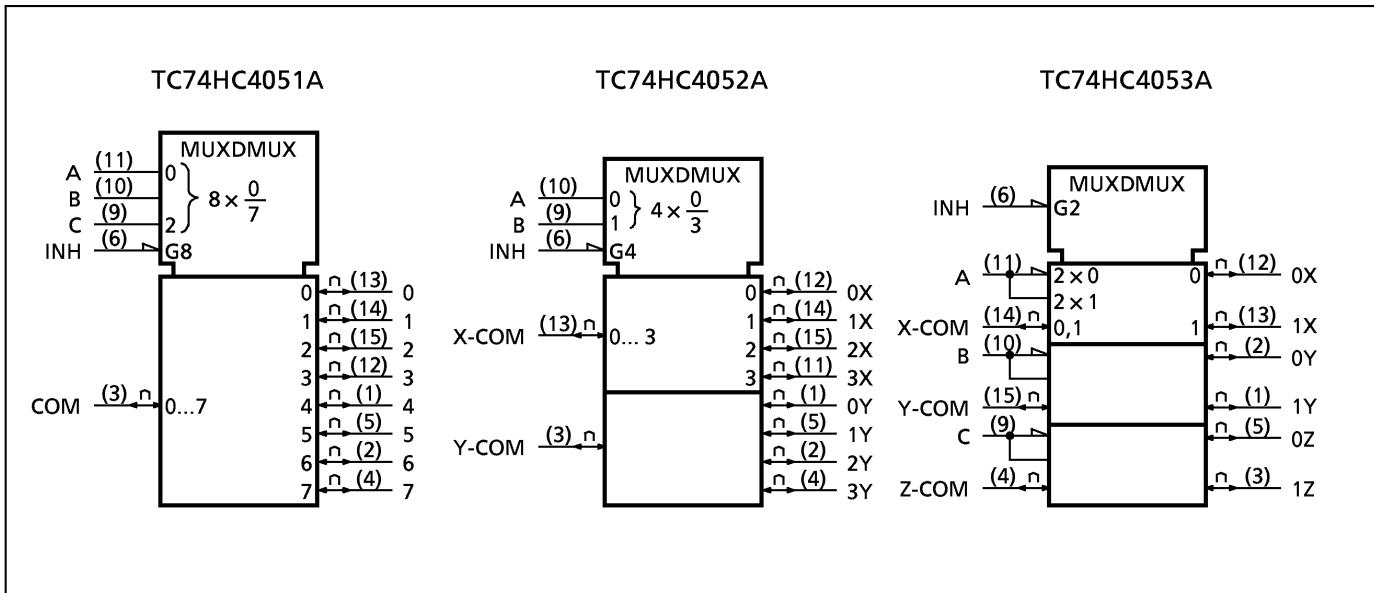
| CONTROL INPUTS | | | | "ON" CHANNEL | | |
|----------------|----|---|---|--------------|---------|----------|
| INHIBIT | C* | B | A | HC4051A | HC4052A | HC4053A |
| L | L | L | L | 0 | 0X, 0Y | 0X,0Y,0Z |
| L | L | L | H | 1 | 1X, 1Y | 1X,0Y,0Z |
| L | L | H | L | 2 | 2X, 2Y | 0X,1Y,0Z |
| L | L | H | H | 3 | 3X, 3Y | 1X,1Y,0Z |
| L | H | L | L | 4 | -- | 0X,0Y,1Z |
| L | H | L | H | 5 | -- | 1X,0Y,1Z |
| L | H | H | L | 6 | -- | 0X,1Y,1Z |
| L | H | H | H | 7 | -- | 1X,1Y,1Z |
| H | X | X | X | NONE | NONE | NONE |

X : Don't Care, * : Except HC4052A

SYSTEM DIAGRAM



IEC LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | VALUE | UNIT |
|-------------------------------|-----------------|-------------------------------|------|
| Supply Voltage Range | V_{CC} | -0.5~7 | V |
| Supply Voltage Range | $V_{CC}-V_{EE}$ | -0.5~13 | V |
| Control Input Voltage | V_{IN} | -0.5~ $V_{CC}+0.5$ | V |
| Switch I/O Voltage | $V_{I/O}$ | $V_{EE}-0.5~V_{CC}+0.5$ | V |
| Control Input Diode Current | I_{ICK} | ± 20 | mA |
| I/O Diode Current | I_{IOK} | ± 20 | mA |
| Switch through Current | I_T | ± 25 | mA |
| DC V_{CC} or Ground Current | I_{CC} | ± 50 | mA |
| Power Dissipation | P_D | 500 (DIP)* / 180 (SOP, TSSOP) | mW |
| Storage Temperature | T_{stg} | -65~150 | °C |

*500mW in the range of $T_a = -40^{\circ}\text{C} \sim 65^{\circ}\text{C}$. From $T_a = 65^{\circ}\text{C}$ to 85°C a derating factor of $-10\text{mW}/^{\circ}\text{C}$ shall be applied until 300mW.

RECOMMENDED OPERATING CONDITIONS

| PARAMETER | SYMBOL | VALUE | UNIT |
|----------------------------------|-----------------|---|------|
| Supply Voltage Range | V_{CC} | 2~6 | V |
| Supply Voltage Range | V_{EE} | -6~0 | V |
| Supply Voltage Range | $V_{CC}-V_{EE}$ | 2~12 | V |
| Control Input Voltage | V_{IN} | 0~ V_{CC} | V |
| Switch I/O Voltage | $V_{I/O}$ | $V_{EE} \sim V_{CC}$ | V |
| Operating Temperature | T_{opr} | -40~85 | °C |
| Control Input Rise and Fall Time | t_r, t_f | 0~1000 ($V_{CC} = 2.0\text{V}$) 0~500 ($V_{CC} = 4.5\text{V}$) 0~400 ($V_{CC} = 6.0\text{V}$) | ns |

DC ELECTRICAL CHARACTERISTICS

| PARAMETER | SYMBOL | TEST CONDITION | V_{EE} (V) | V_{CC} (V) | Ta = 25°C | | | Ta = -40~85°C | | UNIT |
|--|-----------------|---|----------------------------|--------------------------|----------------------|-----------------------|-----------------------|----------------------|-------------------------|----------|
| | | | | | MIN. | TYP. | MAX. | MIN. | MAX. | |
| High - Level Control Input Voltage | V_{IHC} | | 2.0 4.5 6.0 | 2.0 4.5 6.0 | 1.50 3.15 4.20 | — — — | — — — | 1.50 3.15 4.20 | — — — | V |
| Low - Level Control Input Voltage | V_{ILC} | | | 2.0 4.5 6.0 | — — — | — — — | 0.50 1.35 1.80 | — — — | 0.50 1.35 1.80 | |
| ON Resistance | R_{ON} | $V_{IN} = V_{ILC}$ or V_{IHC} $V_{I/O} = V_{CC}$ to V_{EE} $I_{I/O} \leq 2mA$ | GND —4.5 —6.0 | 4.5 4.5 6.0 | — — — | 85 55 50 | 180 120 100 | — — — | 225 150 125 | Ω |
| | | $V_{IN} = V_{ILC}$ or V_{IHC} $V_{I/O} = V_{CC}$ or V_{EE} $I_{I/O} \leq 2mA$ | GND GND —4.5 —6.0 | 2.0 4.5 4.5 6.0 | — — — — | 150 70 50 45 | — 150 100 80 | — — — — | 190 125 100 | |
| Difference of ON Resistance Between Switches | ΔR_{ON} | $V_{IN} = V_{ILC}$ or V_{IHC} $V_{I/O} = V_{CC}$ to V_{EE} $I_{I/O} \leq 2mA$ | GND —4.5 —6.0 | 4.5 4.5 6.0 | — — — | 10 5 5 | 30 12 10 | — — — | 35 15 12 | nA |
| Input / Output Leakage Current (SWITCH OFF) | I_{OFF} | $V_{OS} = V_{CC}$ or GND $V_{IS} = GND$ or V_{CC} $V_{IN} = V_{ILC}$ or V_{IHC} | GND —6.0 | 6.0 6.0 | — — | — — | ± 60 ± 100 | — — | ± 600 ± 1000 | |
| Switch Input Leakage Current (SWITCH ON) | I_{IZ} | $V_{OS} = V_{CC}$ or GND $V_{IN} = V_{ILC}$ or V_{IHC} | GND —6.0 | 6.0 6.0 | — — | — — | ± 60 ± 100 | — — | ± 600 ± 1000 | |
| Control Input Current | I_{IN} | $V_{IN} = V_{CC}$ or GND | GND | 6.0 | — | — | ± 0.1 | — | ± 1.0 | μA |
| Quiescent Supply Current | I_{CC} | $V_{IN} = V_{CC}$ or GND | GND —6.0 | 6.0 6.0 | — — | — — | 4.0 8.0 | — — | 40.0 80.0 | |

AC ELECTRICAL CHARACTERISTICS ($C_L = 50\text{pF}$, Input $t_r = t_f = 6\text{ns}$, GND = 0V)

| PARAMETER | SYMBOL | TEST CONDITION | Ta = 25°C | | | Ta = -40~85°C | | UNIT | |
|---|------------------------|-------------------------|----------------------------|--------------------------|--------------------|----------------------|---------------------|----------------------|----------------|
| | | | V_{EE} (V) | V_{CC} (V) | MIN. | TYP. | MAX. | | |
| Phase difference between Input and Output | ϕ I/O | ALL TYPES | GND GND GND — 4.5 | 2.0 4.5 6.0 4.5 | — — 5 4 | 25 6 10 — | 60 12 — — | 75 15 13 — | |
| Output Enable Time | t_{pzL} t_{pzH} | *1 4051 | GND GND GND — 4.5 | 2.0 4.5 6.0 4.5 | — — 15 18 | 64 18 38 — | 225 45 — — | 280 56 48 — | |
| | | *1 4052 | GND GND GND — 4.5 | 2.0 4.5 6.0 4.5 | — — 15 18 | 64 18 38 — | 225 45 — — | 280 56 48 — | |
| | | *1 4053 | GND GND GND — 4.5 | 2.0 4.5 6.0 4.5 | — — 12 14 | 50 14 38 — | 225 45 — — | 280 56 48 — | |
| Output Disable Time | t_{plZ} t_{phZ} | *1 4051 | GND GND GND — 4.5 | 2.0 4.5 6.0 4.5 | — — 28 29 | 100 33 43 — | 250 50 — — | 315 63 54 — | |
| | | *1 4052 | GND GND GND — 4.5 | 2.0 4.5 6.0 4.5 | — — 28 29 | 100 33 43 — | 250 50 — — | 315 63 54 — | |
| | | *1 4053 | GND GND GND — 4.5 | 2.0 4.5 6.0 4.5 | — — 26 26 | 95 30 38 — | 225 45 — — | 280 56 48 — | |
| Control Input Capacitance | C_{in} | ALL TYPES | — | — | — | 5 | 10 | — | 10 |
| COMMON Terminal Capacitance | C_{IS} | 4051 4052 4053 | — 5.0 | 5.0 | — — — | 36 19 11 | 70 40 20 | — | 70 40 20 |
| SWITCH Terminal Capacitance | C_{os} | 4051 4052 4053 | — 5.0 | 5.0 | — — — | 7 7 7 | 15 15 15 | — | 15 15 15 |
| Feedthrough Capacitance | C_{ios} | 4051 4052 4053 | — 5.0 | 5.0 | — — — | 0.95 0.85 0.75 | 2 2 2 | — | 2 2 2 |
| Power Dissipation Capacitance | C_{PD} | *2 4051 4052 4053 | GND | 5.0 | — — — | 70 71 67 | — — — | — | — |

* 1: $R_L = 1\text{k}\Omega$ * 2: C_{PD} is defined as the value of the internal equivalent capacitance of IC which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

ANALOG SWITCH CHARACTERISTICS (GND = 0V, Ta = 25°C)

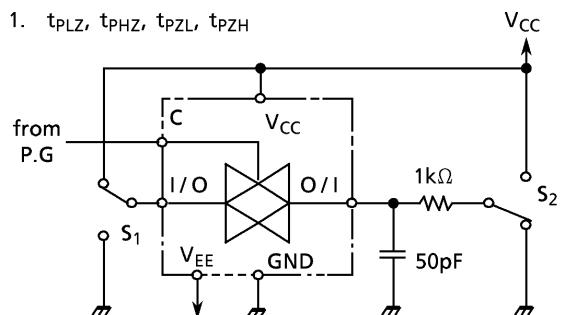
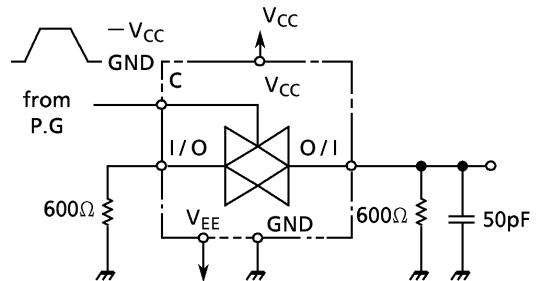
| PARAMETER | SYMBOL | TEST CONDITION | V _{EE} (V) | V _{CC} (V) | TYP. | UNIT | |
|--|------------------|--|---|-----------------------|-------------------------|---|-----|
| Sine Wave Distortion (T.H.D) | | R _L = 10kΩ C _L = 50pF f _{IN} = 1kHz V _{IN} = 4.0V _{P-P} V _{IN} = 8.0V _{P-P} V _{IN} = 11.0V _{P-P} | -2.25 -4.5 -6.0 | 2.25 4.5 6.0 | 0.025 0.020 0.018 | % | |
| Frequency Responce (Switch ON) | f _{MAX} | Adjust f _{IN} Voltage to obtain 0dBm at V _{OS} Increase f _{IN} Frequency until dB Meter reads -3dB R _L = 50Ω, C _L = 10pF f _{IN} = 1MHz, Sine Wave | *1 ALL *2 4051 4052 4053 *1 ALL *2 4051 4052 4053 *1 ALL *2 4051 4052 4053 | -2.25 -4.5 -6.0 | 2.25 4.5 6.0 | 120 45 70 95 190 70 110 150 200 85 140 190 | MHz |
| Feed through Attenuation (Switch OFF) | | V _{in} is centered at (V _{CC} - V _{EE}) / 2 Adjust input for 0dBm R _L = 600Ω, C _L = 50pF f _{IN} = 1MHz, Sine Wave | -2.25 -4.5 -6.0 | 2.25 4.5 6.0 | -50 -50 -50 | dB | |
| Crosstalk (Control Input to Signal Output) | | R _L = 600Ω, C _L = 50pF f _{IN} = 1MHz, Square Wave (t _r = t _f = 6ns) | -2.25 -4.5 -6.0 | 2.25 4.5 6.0 | 60 140 200 | mV | |
| Crosstalk (Between any switches) | | Adjust V _{IN} to obtain 0dBm at Input R _L = 600Ω, C _L = 50pF f _{IN} = 1MHz, Sine Wave | -2.25 -4.5 -6.0 | 2.25 4.5 6.0 | -50 -50 -50 | dB | |

* 1 : Input COMMON Terminal, and measured at SWITCH Terminal.

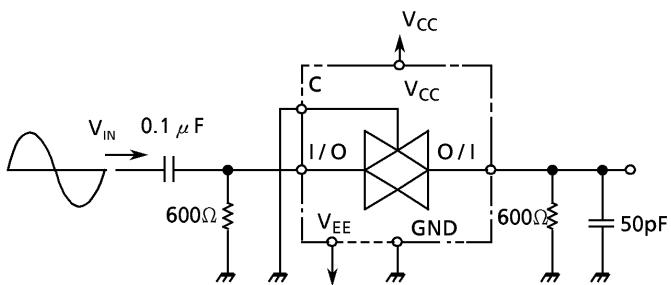
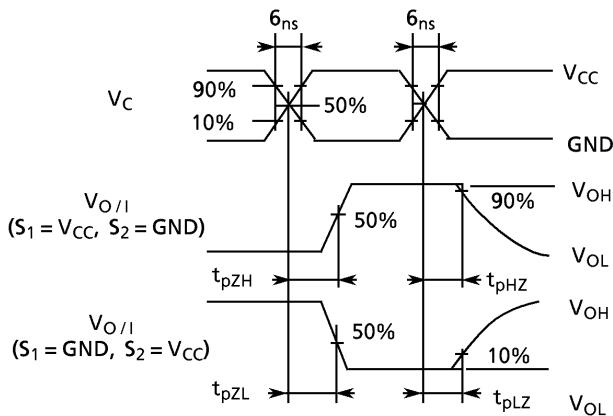
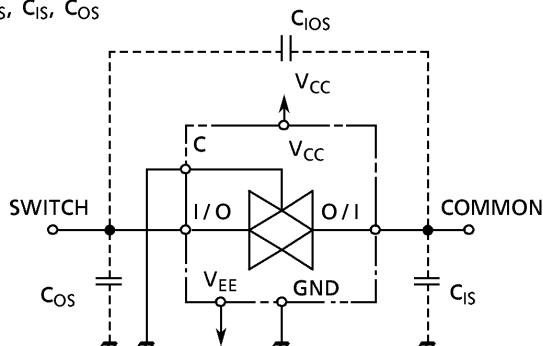
* 2 : Input SWITCH Terminal, and measured at COMMON Terminal.

NOTE : These characteristics are determined by design of devices.

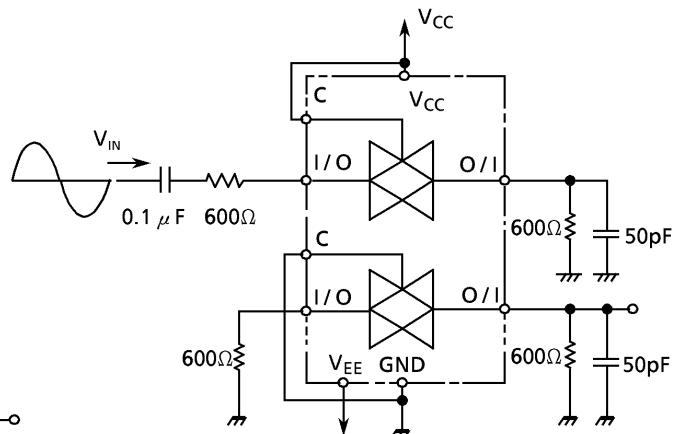
SWITCHING CHARACTERISTICS TEST CIRCUITS

1. t_{PLZ} , t_{PHZ} , t_{PZL} , t_{PZH} 2. CROSS TALK (CONTROL INPUT – SWITCH OUTPUT)
 $f_{IN} = 1\text{MHz}$ duty = 50% $t_r = t_f = 6\text{ns}$ 

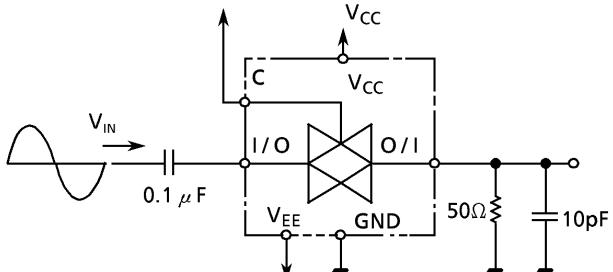
3. FEEDTHROUGH ATTENUATION

4. C_{IOS} , C_{IS} , C_{OS} 

5. CROSS TALK (BETWEEN ANY TWO SWITCHES)

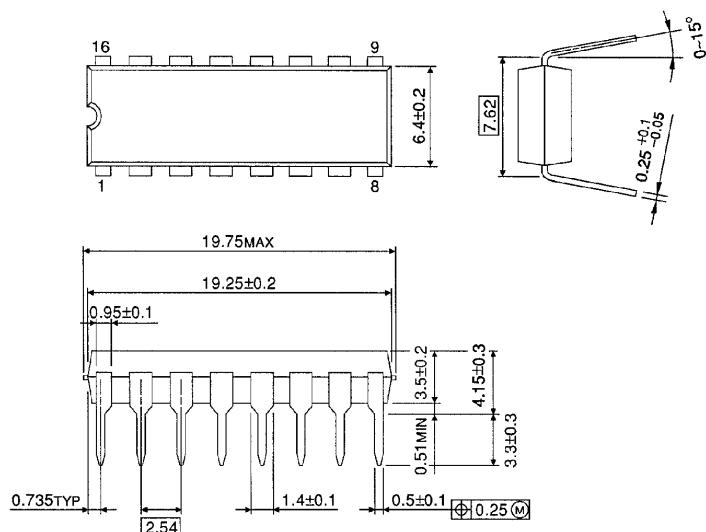


6. FREQUENCY RESPONSE (SWITCH ON)



DIP 16PIN PACKAGE DIMENSIONS (DIP16-P-300-2.54A)

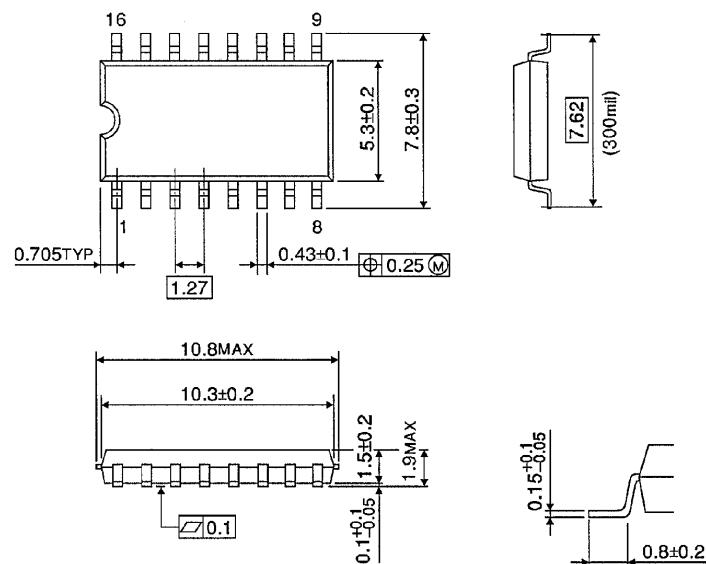
Unit in mm



Weight : 1.00g (Typ.)

SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27)

Unit in mm

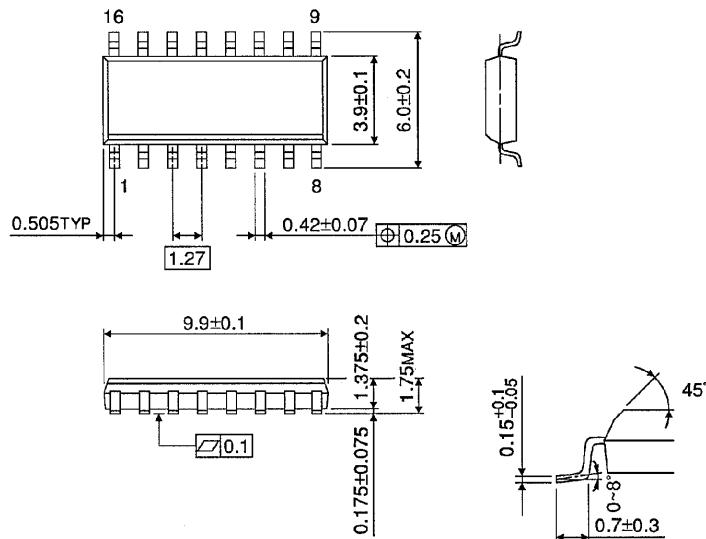


Weight : 0.18g (Typ.)

SOP 16PIN (150mil BODY) PACKAGE DIMENSIONS (SOL16-P-150 -1.27)

Unit in mm

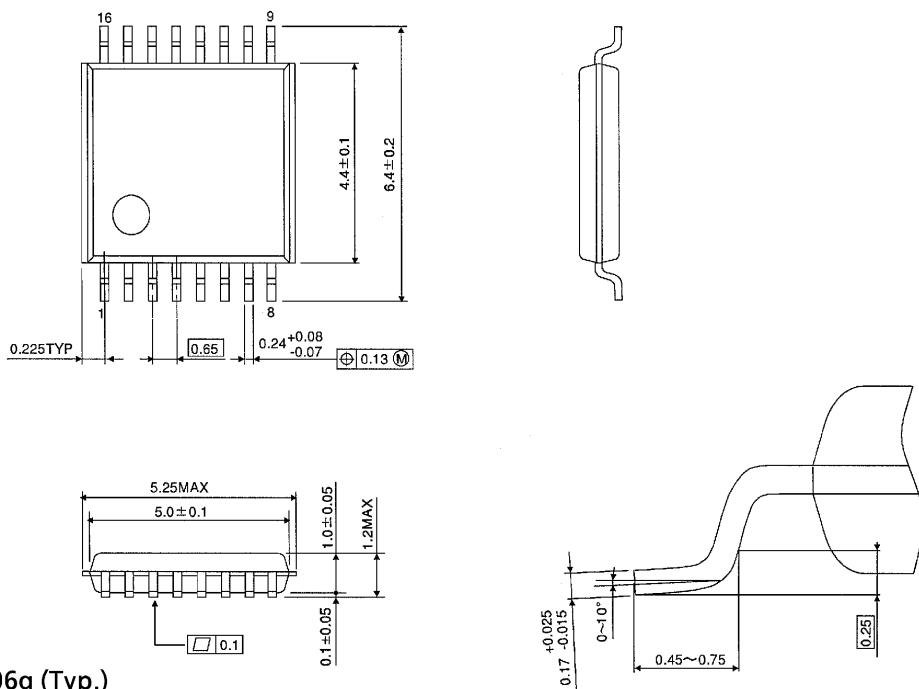
(Note) This package is not available in Japan.



Weight : 0.13g (Typ.)

TSSOP 16PIN PACKAGE DIMENSIONS (TSSOP16-P-0044-0.65)

Unit in mm



Weight : 0.06g (Typ.)

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000707EBA

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